



Image may be representation. See specs for product details.

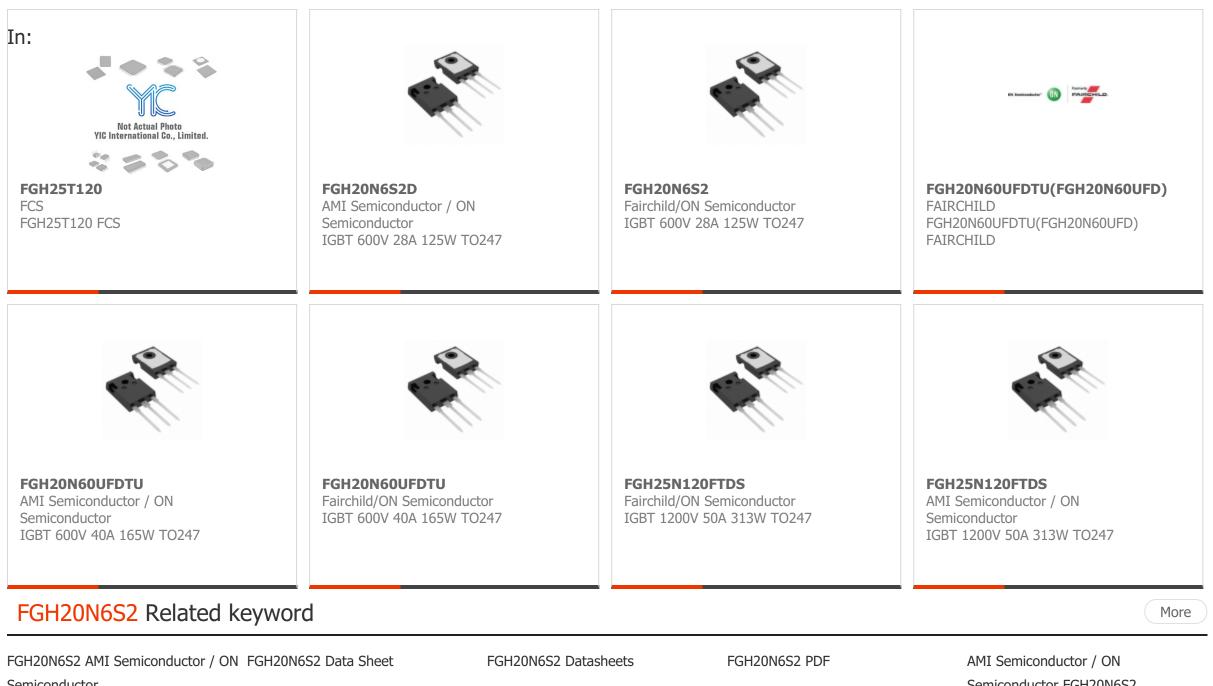
FGH20N6S2

Manufacturer Part Number:	FGH20N6S2
Manufacturer/Brand:	AMI Semiconductor / ON Semiconductor
Part of Description:	IGBT 600V 28A 125W TO247
Datasheets:	FGH20N6S2.pdf
RoHs Status:	Kohs Lead free / RoHS
Stock Condition:	Compliant New original, 6062 pcs Stock Available.
Ship From:	Hong Kong
Shipment Way:	DHL/Fedex/TNT/UPS/EMS

Specifications

Part Number	FGH20N6S2
Manufacturer	AMI Semiconductor / ON Semiconductor
Description	IGBT 600V 28A 125W TO247
Category	Discrete Semiconductor Products > Transistors - IGBTs -
Part Status	6062 pcs Stock
Voltage - Collector Emitter Breakdown (Max)	600V
Vce(on) (Max) @ Vge, Ic	2.7V @ 15V, 7A
Test Condition	390V, 7A, 25 Ohm, 15V
Td (on/off) @ 25°C	7.7ns/87ns
Switching Energy	25μJ (on), 58μJ (off)
Supplier Device Package	TO-247-3
Series	-
Power - Max	125W
Packaging	Tube
Package / Case	TO-247-3
Other Names	FGH20N6S2_NL
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Moisture Sensitivity Level (MSL)	1 (Unlimited)
Lead Free Status / RoHS Status	Lead free / RoHS Compliant
Input Type	Standard
IGBT Type	-
Gate Charge	30nC
Detailed Description	IGBT 600V 28A 125W Through Hole TO-247-3
Current - Collector Pulsed (Icm)	40A
Current - Collector (Ic) (Max)	28A

You May Be Also Be interested



Semiconductor

FGH20N6S2 Electronic FGH20N6S2 Price

FGH20N6S2 Components FGH20N6S2 Manufacturer FGH20N6S2 Distributor

FGH20N6S2 Image FGH20N6S2 Stock

Semiconductor FGH20N6S2 FGH20N6S2 Part FGH20N6S2 Inventory

FGH20N6S2 Picture

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